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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/078,344	02/21/2002	Hajime Nagano	219723US2S 6086	
22850	7590 04/21/2004		EXAMINER	
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C.			NGO, NGAN V	
ALEXANDRIA, VA 22314			ART UNIT	PAPER NUMBER
			2814	,
			DATE MAILED: 04/21/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/078,344	NAGANO ET AL.			
Office Action Summary	Examiner	Art Unit			
	Ngan Ngo	2814			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the co	orrespond nce address			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	66(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from to cause the application to become ABANDONED	ely filed will be considered timely. the mailing date of this communication. 0 (35 U.S.C. § 133).			
Status					
1)⊠ Responsive to communication(s) filed on <u>07 April 2004</u> .					
	-				
Disposition of Claims					
 4) Claim(s) 1-3,5-7,9 and 26 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 1-3,5-7,9 and 26 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement. 					
Application Papers					
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the of Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Examiner	epted or b) objected to by the Edrawing(s) be held in abeyance. See on is required if the drawing(s) is objected	37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.					
Attachment(s)					
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 0404. 	4) Interview Summary (Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:				

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The amendment filed February 12, 2004 has been entered and made of record as paper no. 0204.

Claims 2, 5, and 7 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claims 2, 5, and 7, "said second semiconductor layer" has no antecedent basis.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 and 2 are rejected under 35 U.S.C. 102(b) as being anticipated by Hakey et al (US-6,232,170-B1, cited by Applicants).

Hakey discloses in figures 1(d) and 1(e) a support substrate comprising a first region (16) and a second region (14), a buried oxide (12), a semiconductor layer (10a), an epitaxial layer (22), and an interface between the epitaxial layer and the supporting substrate being set in a portion which lies deeper than the buried oxide layer. As shown in figure 1(d), the second region of the supporting substrate has a surface lower than a surface of the first region of the support substrate.

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The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3, 5-7, 9, and 26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hakey in view of Disney (US-6,127,701, of record).

Hakey discloses in figures 1(d) and 1(e) a support substrate comprising a first region (16) and a second region (14), a buried oxide (12), a semiconductor layer (10a), an epitaxial layer (22), and an interface between the epitaxial layer and the supporting substrate being set in a portion which lies deeper than the buried oxide layer. However, Hakey does not disclose the first and second elements being formed in the first and second regions. Disney discloses that the circuit elements can be formed in two different regions in order to form different type of circuits in different regions. Therefore, it would have been obvious to one of ordinary skill in the art to form different elements in different regions of the support substrate of Hakey's device in order to form different type of circuits as taught by Disney.

In re claim 26, Hakey discloses the deep trench 24 used to form the trench type memory cell of a DRAM. Note line 17, column 5 of Hakey.

Any inquiry concerning this communication should be directed to Examiner Ngan Ngo at telephone number (571) 272-1711. The fax number for the Art unit is (703) 308-7722.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0956.

Ngan Van Ngo Primary Examiner

Ngan Ngo

April 16, 2004